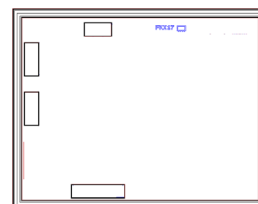


Ultra High Dynamic Range Monolithic Amplifier Die

PHA-202-D+

50Ω 0.3 to 2.7 GHz



The Big Deal

- Ultra High IP3, +46.1 dBm
- Broadband High Dynamic Range without external Matching Components
- Medium power, 1W
- Excellent return loss over 15 dB

Product Overview

PHA-202-D+ (RoHS compliant) is a medium power amplifier die fabricated using E-PHEMT technology and offers extremely high dynamic range over a broad frequency range and with low noise figure. In addition, the PHA-202-D+ has good input and output return loss over a broad frequency range without the need for external matching components and has demonstrated excellent reliability.

Key Features

Feature	Advantages
Broad Band: 0.03 to 2.7 GHz	Broadband covering primary wireless communications bands: Cellular, PCS, LTE
Extremely High IP3 Versus DC power Consumption 46 dBm typical at 1.0 GHz	The PHA-202-D+ matches industry leading IP3 performance relative to device size and power consumption. The combination of the design and E-PHEMT Structure provides enhanced linearity over a broad frequency range as evidence in the IP3 being typically 14-23 dB above the P1dB point. This feature makes this amplifier ideal for use in: • Driver amplifiers for complex waveform up converter paths • Drivers in linearized transmit systems • Secondary amplifiers in ultra High Dynamic range receivers
No External Matching Components Required	Unlike competing products, Mini-Circuits PHA-202-D+ provides Input and Output Return Loss of over 15 dB up to 2 GHz without the need for any external matching components



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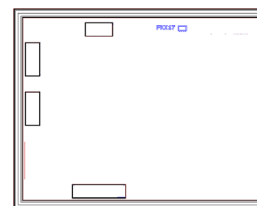
50Ω 0.3 to 2.7 GHz

Product Features

- High IP3, 46.1 dBm typ. at 1 GHz
- Gain, 17.0 dB typ. at 1 GHz
- High Pout, P1dB 30.4 dBm typ. at 1 GHz
- No external matching components required

Typical Applications

- Base station infrastructure
- CATV & DBS
- LTE



+RoHS Compliant

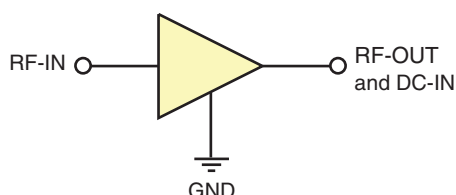
The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

Ordering Information: Refer to Last Page

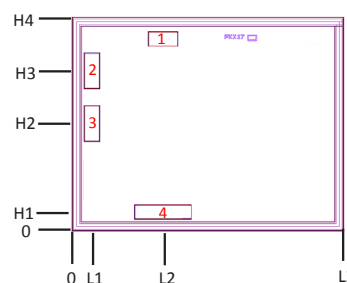
General Description

PHA-202-D+ (RoHS compliant) is a medium power amplifier die fabricated using E-PHEMT technology and offers extremely high dynamic range over a broad frequency range and with low noise figure. In addition, the PHA-202-D+ has good input and output return loss over a broad frequency range without the need for external matching components and has demonstrated excellent reliability.

Simplified Schematic and Pad description



Bonding Pad Position



Pad#	Function	Description
1	RF-IN	RF input pad. This pad requires the use of an external DC blocking capacitor chosen for the frequency of operation
4	RF-OUT & DC-IN	RF output pad and bias pad. DC voltage is present on this pad, therefore, a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection.
2,3	GND	Connections to ground. Bottom of die.

Note: 1. Bond Pad material - Gold
2. Bottom of Die - Gold plated

Dimensions in μm, Typical

L1	L2	L3	H1	H2	H3	H4	Thickness	Width	Length	RF-IN Bond Pad Size	RF-OUT + DC-IN Bond Pad Size	Ground Bond Pad Size
77.5	436	1325	73	517.5	782.5	1030	100	1325	1030	140 x 70	280 x 65	70 x 170



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REV. OR
M163097
PHA-202-D+
MCL NY
171017
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Electrical Specifications at 25°C, 50 ohms, unless noted

Parameter	Condition (MHz)	Vd=11V ¹			Units
		Min.	Typ.	Max.	
Frequency range		0.03		2.7	GHz
Gain	30		18.3		dB
	500		17.9		
	1000		17.0		
	2000		14.7		
	2700		12.7		
Input return loss	30		21.2		dB
	500		21.7		
	1000		19.5		
	2000		20.3		
	2700		14.9		
Output return loss	30		15.1		dB
	500		16.4		
	1000		19.4		
	2000		22.5		
	2700		9.8		
Reverse isolation	2000		23		dB
Output power @ 1dB compression	30		28.4		dBm
	500		30.2		
	1000		30.4		
	2000		28.1		
	2700		25.7		
Output IP3 ²	30		51.0		dBm
	500		48.5		
	1000		46.1		
	2000		43.2		
	2700		39.4		
Noise figure	30		3.2		dB
	500		3.3		
	1000		3.5		
	2000		4.4		
	2700		5.4		
Device operating voltage			11		V
Device operating current		—	350	416	mA
Device current variation vs voltage ³			0.0485		mA/mV
Thermal Resistance, junction-to-ground lead at 85°C stage temp.			16.1		°C/W

1. Measured on Mini-Circuits Characterization test board. Die package in 5x6mm, 8-lead MCLP package and soldered on test board MB018

2. Tested at Pout=16dBm / tone.

3. (Current at 11.5V-current - Current at 10.5V)/1000

Absolute Maximum Ratings⁴

Parameter	Ratings
Operating Temperature (ground lead)	-40°C to 85°C
Junction Temperature	179°C
Power Dissipation	5.8W
Input Power (CW) ¹	+24 dBm (5 minutes max.) +19 dBm (continuous)
DC Voltage on Pad#4 ¹	14V

4 Permanent damage may occur if any of these limits are exceeded.
Electrical maximum ratings are not intended for continuous normal operation.



Characterization Test Circuit

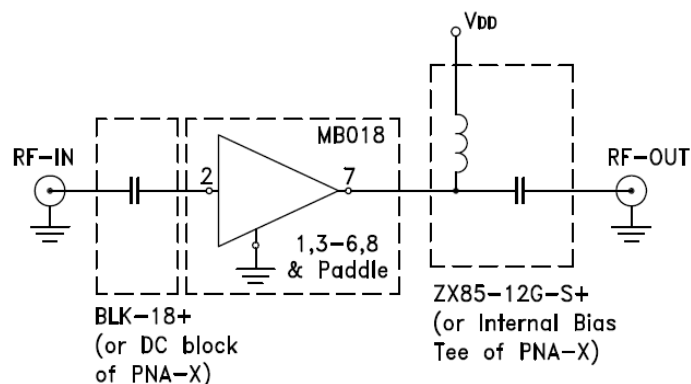


Fig 1. Characterization Circuit

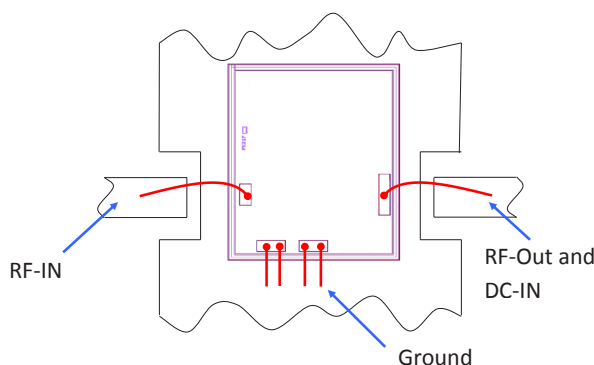
Note: This block diagram is used for characterization. (Die packaged in 5x6mm, 8-lead MCLP package and soldered on Mini-Circuits Characterization test board MB018)

Gain, Return loss, Output power at 1dB compression (P1 dB), output IP3 (OIP3) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer.

Conditions:

1. Gain and Return loss: Pin= -25dBm
2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 16 dBm/tone at output.

Assembly Diagram



Assembly and Handling Procedure

1. Storage
Dice should be stored in a dry nitrogen purged desiccators or equivalent.
2. ESD
MMIC E-PHEMT amplifier dice are susceptible to electrostatic and mechanical damage. Die are supplied in antistatic protected material, which should be opened in clean room conditions at an appropriately grounded anti-static workstation. Devices need careful handling using correctly designed collets, vacuum pickup tips or sharp antistatic tweezers to deter ESD damage to dice.
3. Die Attach
The Die mounting surface must be clean and flat. Using conductive silver filled epoxy, recommended epoxies are DieMat DM6030HK-PT/H579 or Ablestik 84-1LMISR4. Apply sufficient epoxy to meet required epoxy bond line thickness, epoxy fillet height and epoxy coverage around total Die periphery. Parts shall be cured in a nitrogen filled atmosphere per manufacturer's cure condition. It is recommended to use antistatic Die pick up tools only.
4. Wire Bonding
Bond pad openings in the surface passivation above the bond pads are provided to allow wire bonding to the dice gold bond pads. Thermosonic bonding is used with minimized ultrasonic content. Bond force, time, ultrasonic power and temperature are all critical parameters. Suggested wire is pure gold, 1 mil diameter. Bonds must be made from the bond pads on the Die to the package or substrate. All bond wires should be kept as short as low as reasonable to minimize performance degradation due to undesirable series inductance.

additional information is available on our dash board.

*Known Good Dice ("KGD") means that the dice in question have been subjected to Mini-Circuits DC test performance criteria and measurement instructions and that the parametric data of such dice fall within a predefined range. While DC testing is not definitive, it does help to provide a higher degree of confidence that dice are capable of meeting typical RF electrical parameters specified by Mini-Circuits.

** Tested in industry standard 5x6mm, 8-lead MCLP package

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